

ITERATIVE LEARNING CONTROL OF SUPERSATURATION IN BATCH COOLING CRYSTALLIZATION

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Outline

- 1 Batch Crystallization
- 2 Iterative Learning Control
- 3 Simulation Results
- 4 Conclusions

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Batch Crystallization

Process Description

Separation and purification process of industrial interest.

A solution is cooled down, solid material (crystals) produced.

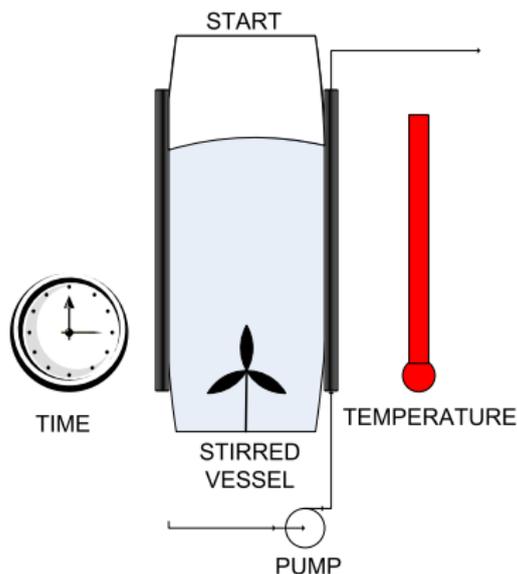
- Hot solution fed into the vessel.
- Cool to seeding temperature.
- Introduce seeds.
- Cool to final temperature.
Crystal growth (and nucleation).
- Remove final product.

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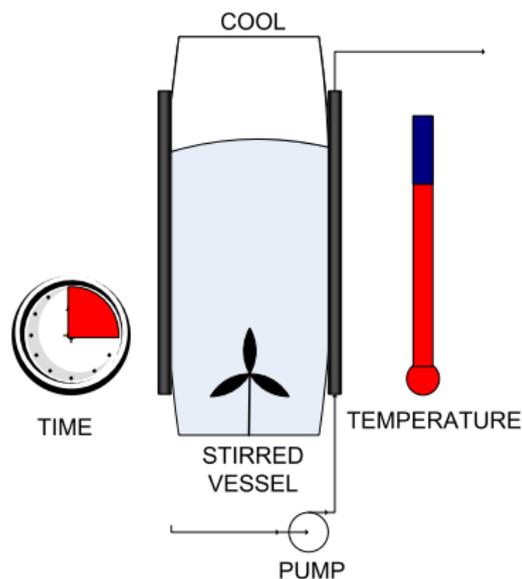
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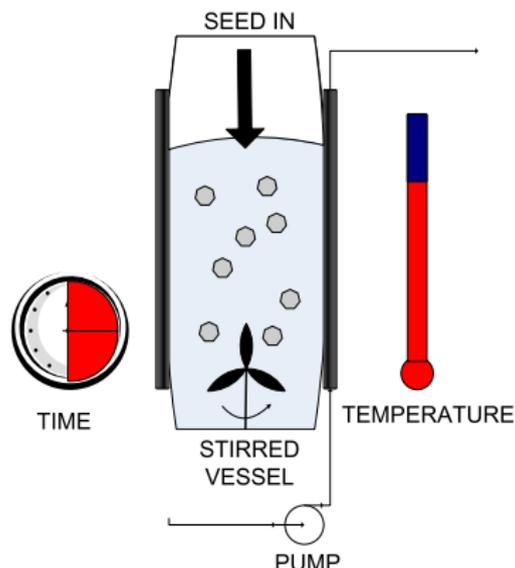
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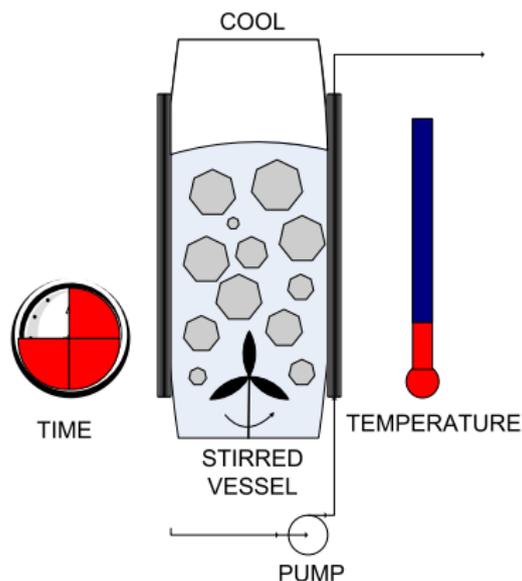
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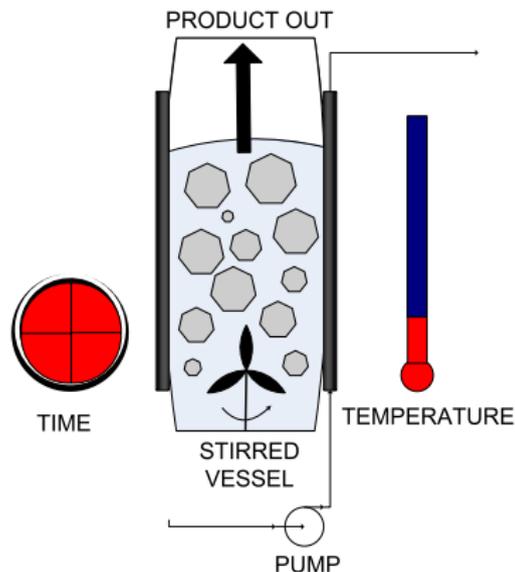
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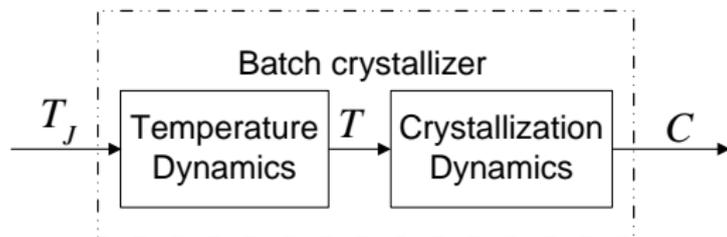
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Batch Crystallization

Modeling

Process (after seeding) described by

- Temperature Dynamics (linear, known or easy to estimate)
- Crystallization Dynamics (nonlinear PDE, parametric + structural uncertainties possible)



Batch Crystallization

Modeling

Input

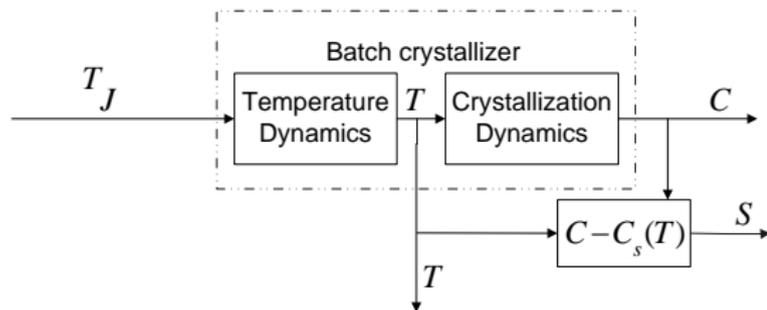
- Jacket temperature T_J

Measured Output

- Vessel Temperature T
- Concentration C

Control Output

- Supersaturation
 $S = C - C_s(T)$



Disturbances

- Low frequency disturbance on the input
- White measurement noise on the outputs

Batch Crystallization

Modeling

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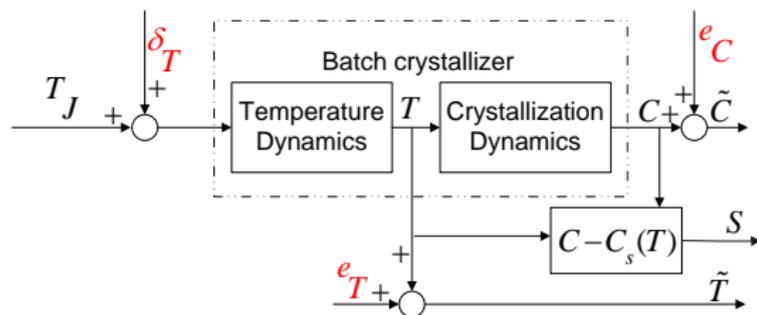
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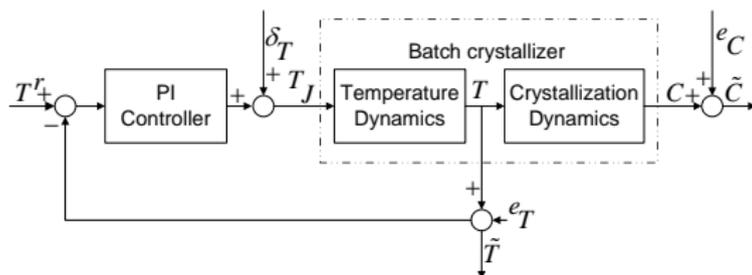
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Batch Crystallization

Control Strategies: industrial practice

Only the crystallizer **temperature** is measured and controlled on-line.
In some cases, T control does not satisfy all requirements.



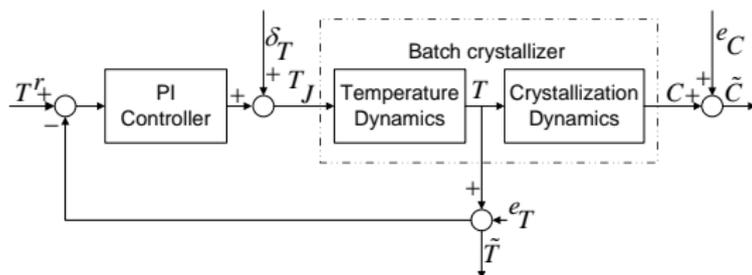
Advanced strategies in literature. They rely on on-line measurements.
Not always available in practice.

Alternative approach based on Iterative Learning Control.

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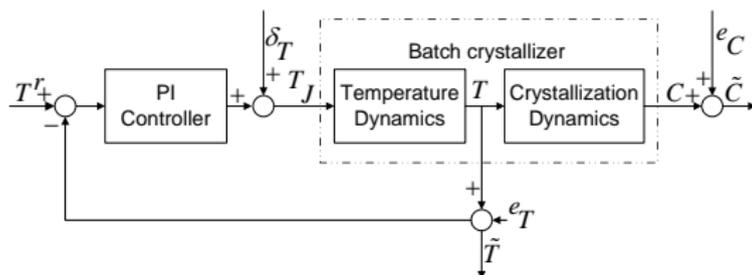
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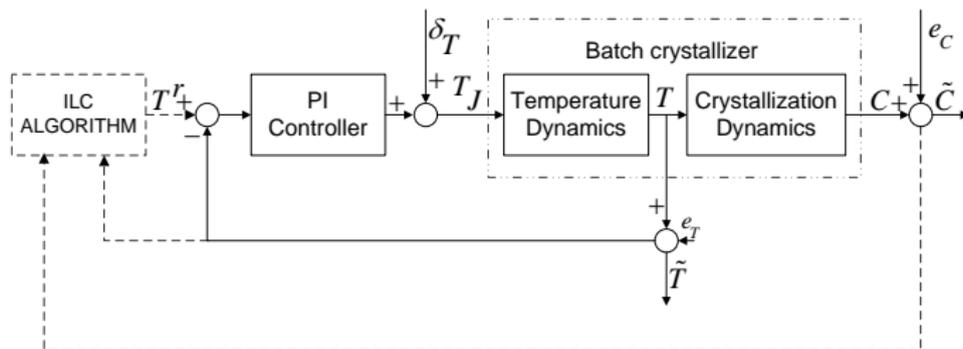
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Iterative Learning Control

Control Scheme

ILC control strategy. \mathbf{T}_k^r updated from batch to batch.

- Can use measurements available at the end of the batch.
- Built on top of the standard industrial T control.



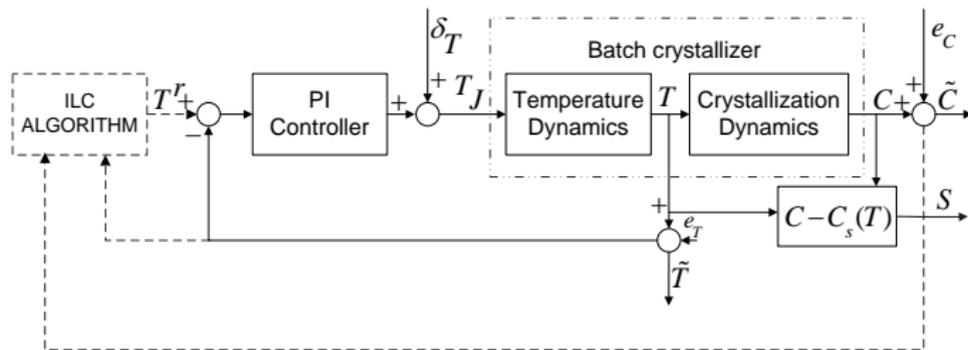
- Objective for batch k : tracking of supersaturation profile \bar{S}_k .

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Iterative Learning Control

General Idea

Based on an **additive correction** of a **nominal model** from \mathbf{T}^r to \mathbf{S} .

$$\begin{array}{ll} \hat{S}(\mathbf{T}^r) & \textit{nominal model} \\ \hat{S}_k(\mathbf{T}^r) \triangleq \hat{S}(\mathbf{T}^r) + \alpha_k & \textit{corrected model} \end{array}$$

Note:

- \mathbf{T}^r, α vectors of samples $\in \mathbb{R}^N$ ($N = \text{batch length}$)

α can compensate the nominal model for

- model mismatch (along a particular trajectory)
- effect of repetitive disturbances

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Iterative Learning Control

Correction vector

How to obtain the correction vector?

- In principle, “match” the last measurement.

$$\alpha_k = \tilde{\mathbf{S}}_k - \hat{\mathbf{S}}(\mathbf{T}^r) = \text{model error}$$

Due to disturbances on $\tilde{\mathbf{S}}_k$, might not be a good solution.

- Take into account the deviation from α_{k-1} .

$$\alpha_k = \arg \min_{\alpha \in \mathbb{R}^N} \|\tilde{\mathbf{S}}_k - (\hat{\mathbf{S}}(\mathbf{T}^r) + \alpha)\|_{Q_\alpha}^2 + \|\alpha - \alpha_{k-1}\|_{S_\alpha}^2$$

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Iterative Learning Control

Algorithm

Steps of the ILC algorithm. At each batch k :

- 1 \mathbf{T}_k^r is set as the input to the PI controller, the batch is executed.
 $\tilde{\mathbf{S}}_k$ is estimated from measurements.
- 2 An additive correction of the nominal model is performed:
 $\hat{\mathbf{S}}_k(\mathbf{T}^r) \triangleq \hat{\mathbf{S}}(\mathbf{T}^r) + \boldsymbol{\alpha}_k$.
- 3 The corrected model is used to design \mathbf{T}_{k+1}^r for the next batch:

$$\mathbf{T}_{k+1}^r = \arg \min_{\mathbf{T}^r \in \mathbb{R}^N} \|\bar{\mathbf{S}}_{k+1} - \hat{\mathbf{S}}_k(\mathbf{T}^r)\|^2 + \lambda \|\mathbf{T}^r - \mathbf{T}_k^r\|^2$$

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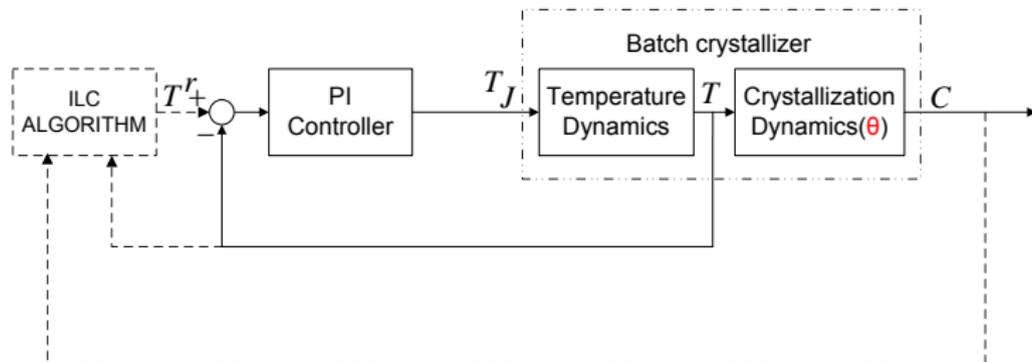
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Simulation Results

Cases

Simulation study in four cases

Case 1: No disturbances, parametric model mismatch

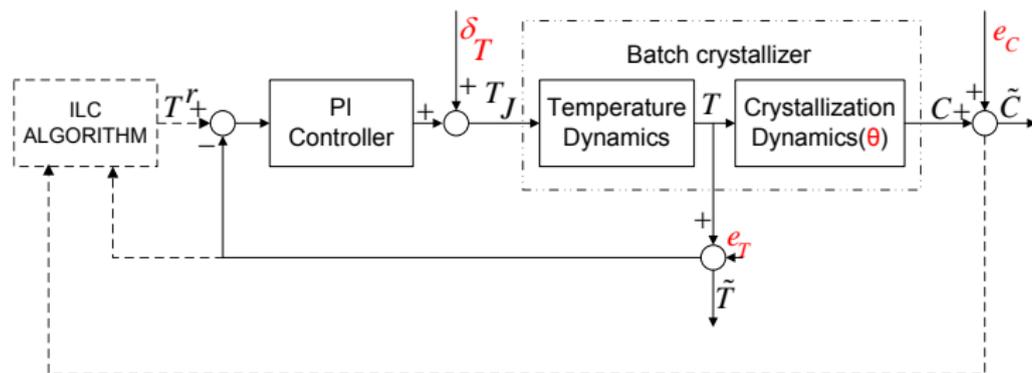


Simulation Results

Cases

Simulation study in four cases

Case 2: Disturbances + parametric model mismatch

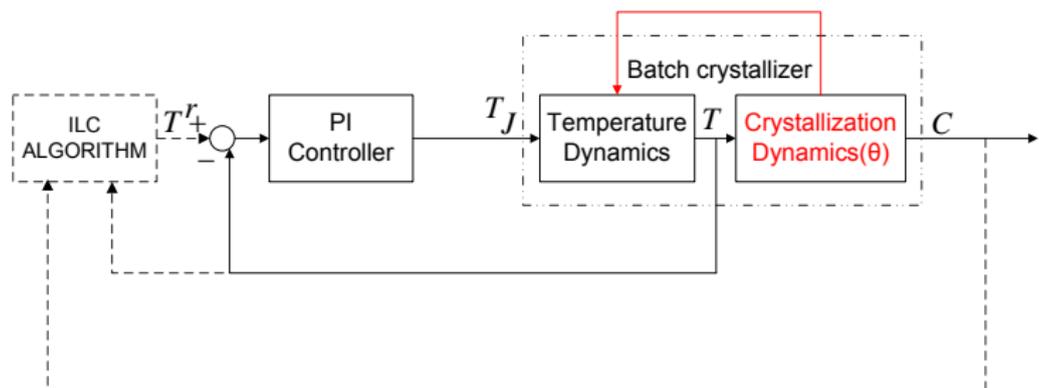


Simulation Results

Cases

Simulation study in four cases

Case 3: No disturbances, structural model mismatch

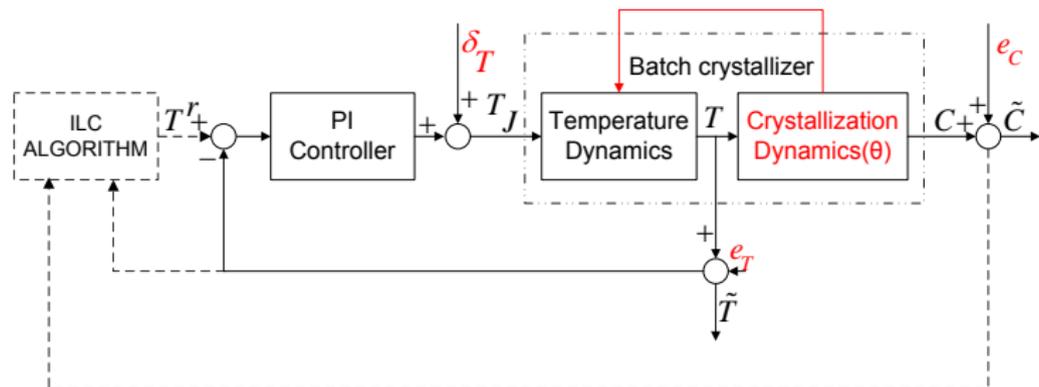


Simulation Results

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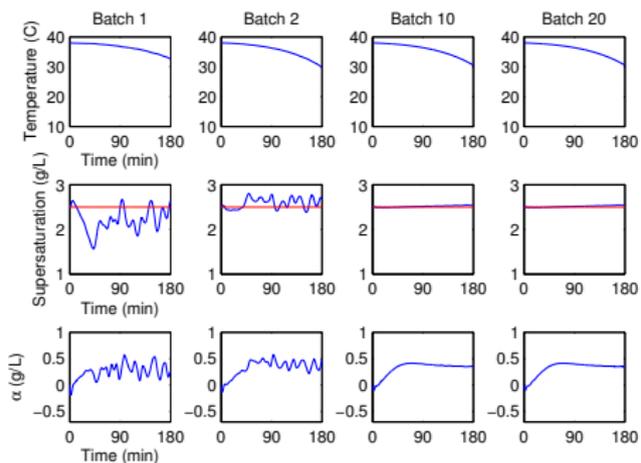
Case 4: Disturbances + structural model mismatch



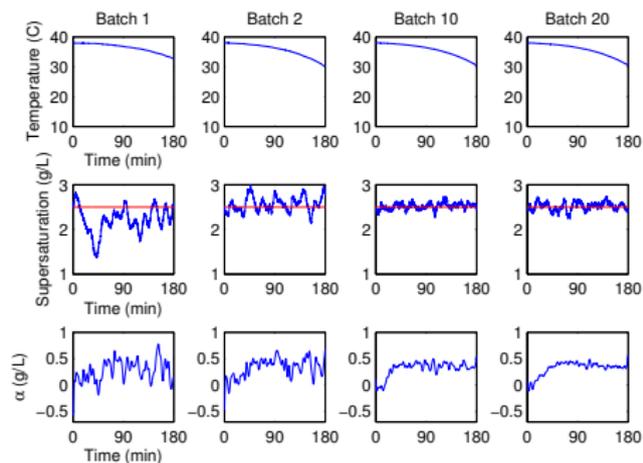
Simulation Results

Cases 1 & 2

Case 1



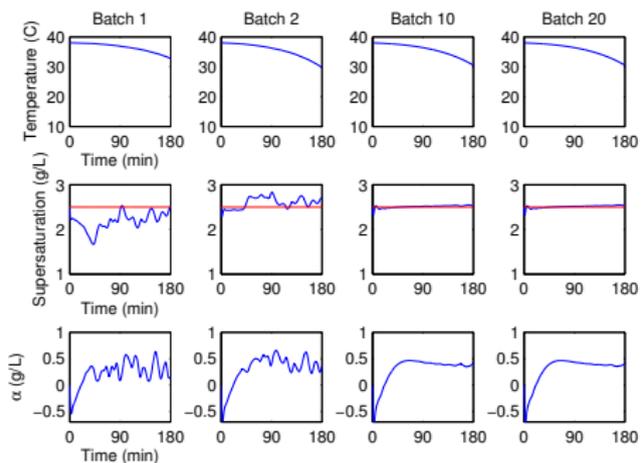
Case 2



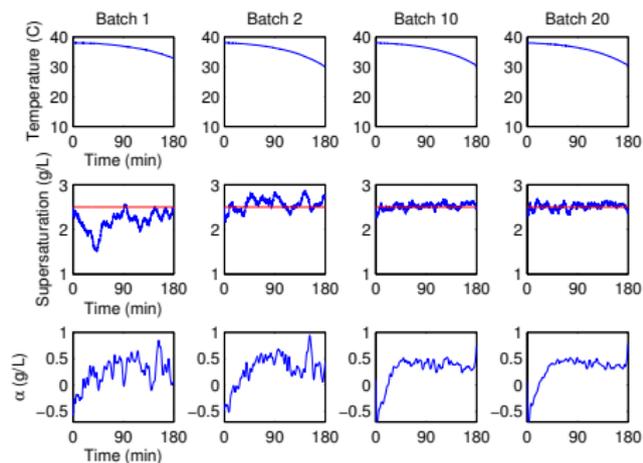
Simulation Results

Cases 2 & 4

Case 2



Case 4



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Conclusions

An Iterative Learning Control scheme for batch cooling crystallization.

- Can use measurements available at the end of a batch.
- Built on top of standard T control
- Can cope with model mismatches and disturbances.

Future/current work

- Practical implementation.
- Control more properties (growth rate, CSD).
- Improve the tuning of the algorithm.
- Comparison with parametric estimation.

Thank you.
Questions?